

STZ6.2N

Diodes

Zener diode
STZ6.2N

●Applications

Constant voltage control
Noise suppression on signal line

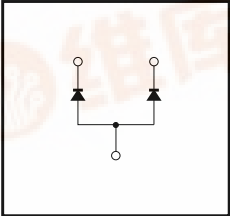
●Features

- 1) Small surface mounting type. (SMD3)
- 2) Multiple diodes with common anode configuration.
- 3) High reliability.

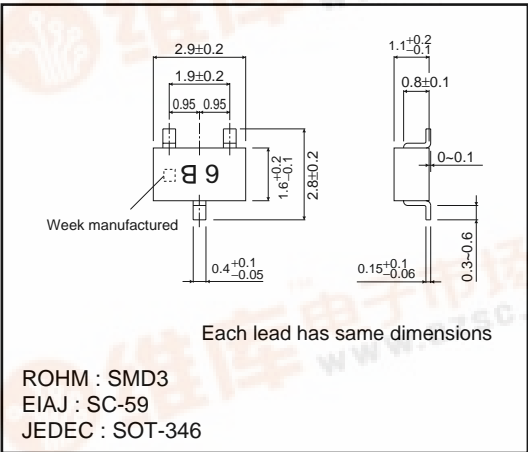
●Construction

Silicon epitaxial planar

●Circuit



●External dimensions (Units : mm)



●Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
Power dissipation*	P	200	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55~+150	°C

*Total of 2 elements

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Zener voltage	Vz	5.81	—	6.40	V	Iz=5mA
Reverse current	Ir	—	—	1.00	μA	VR=3.0V
Operating resistance	Zz	—	—	60	Ω	Iz=5mA
Rising operating resistance	Zzk	—	—	100	Ω	Iz=0.5mA

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●Electrical characteristic curves (Ta = 25°C)

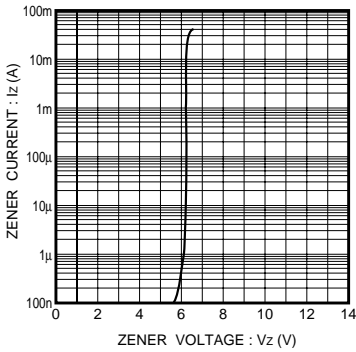


Fig. 1 Zener voltage characteristics

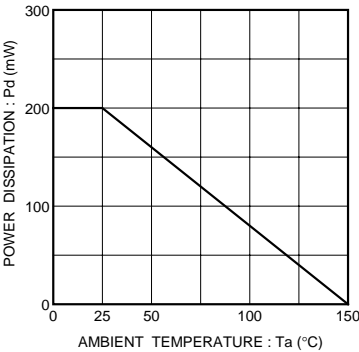


Fig. 2 Derating curve